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Efficient and stable solution-processed planar perovskite solar cells via contact passivation

Hairen Tan,¹ Ankit Jain,¹ Oleksandr Voznyy,¹ Xinzheng Lan,¹ F. Pelayo García de Arquer,¹ James Z. Fan,¹ Rafael Quintero-Bermudez,¹ Mingjian Yuan,¹ Bo Zhang,¹ Yicheng Zhao,¹ Fengjia Fan,¹ Peicheng Li,² Li Na Quan,¹ Yongbiao Zhao,² Zheng-Hong Lu,² Zhenyu Yang,¹ Sjoerd Hoogland,¹ Edward H. Sargent^{1*}

¹Department of Electrical and Computer Engineering, University of Toronto, 35 St George Street, Toronto, Ontario M5S 1A4, Canada. ²Department of Materials Science and Engineering, University of Toronto, 184 College Street, Toronto, Ontario M5S 3E4, Canada.

*Corresponding author. Email: ted.sargent@utoronto.ca

Planar perovskite solar cells made entirely via solution-processing at low temperatures (<150°C) offer promise for simple manufacturing, compatibility with flexible substrates, and perovskite-based tandem devices; however, they require an electron-selective layer that performs well with similar processing. We report a contact passivation strategy using chlorine-capped TiO₂ colloidal nanocrystal (NC) film that mitigates interfacial recombination and improves interface binding in low-temperature planar solar cells. We fabricated solar cells with certified efficiencies of 20.1% and 19.5% for active areas of 0.049 and 1.1 square centimeters, respectively, achieved via low-temperature solution processing. Solar cells with efficiency >20% retained 90% (97% after dark recovery) of their initial performance after 500 hours continuous room-temperature operation at their maximum power point under one-sun illumination.

Metal halide perovskite solar cells (PSCs) have attracted extensive research interest for next-generation solution-processed photovoltaic (PV) devices because of their high solar-to-electric power conversion efficiency (PCE) and low fabrication cost (1–4). The top-performing PSCs, which have reached a certified PCE of 22.1%, have relied on high-temperature-sintered (450°C to 550°C) mesoporous TiO₂ as electron-selective layer (ESL) (5–7). However, this high-temperature processing makes manufacture more complex and hampers the development of flexible modules and perovskite-based monolithic tandem devices. To overcome this limitation, researchers have pursued planar PSCs that exploit low-temperature (typically < 150°C) solution-processed charge selective layers. Metal oxide materials such as TiO₂, ZnO, SnO₂, and Zn₂SnO₄ colloidal nanoparticles synthesized at low temperatures have commonly been used as the ESL (8–16). Very recently, high-efficiency (certified 19.9%), small-area PSCs have been achieved using low-temperature processed SnO₂ (17, 18).

Unfortunately, long-term device operational stability has remained far inferior to that of counterpart devices made using high-temperature-processed ESLs (19–22). Furthermore, PSCs having both high efficiency and large area, required for industrialization, have yet to be demonstrated in low-temperature planar PSCs (best large-area device uncertified PCE of 14.5% for PSCs using low-temperature-processed ESL; best large-area device certified PCE of 19.7%; however, these relied on high-temperature-sintered mesoporous TiO₂) (23–25).

We reasoned that performance and stability loss in low-temperature planar PSCs could arise from imperfect interfaces and charge recombination between the selective contact at the illumination side and the perovskite film grown on top (4, 26, 27), since the perovskite active layers themselves have excellent long-term photostability upon addition of formamidinium (FA), Cs, and Br ions (19–22, 28). Indeed, once the impressively long photocarrier diffusion lengths in perovskite films are achieved, attention must shift to perfecting the interface (29–32). We reasoned that deep trap states present at the perovskite/ESL interface could potentially be addressed by passivating the interface between the charge selective contact and the perovskite absorber.

Here we devise a simple and effective interface passivation method that leads to efficient and stable low-temperature-processed planar PSCs. Chlorine-capped TiO₂ colloidal nanocrystal (NC) films processed < 150°C were used as the ESL. The chloride additive in perovskite precursor solutions enhances grain-boundary passivation in MAPbI_{3-x}Cl_x (MA, methylammonium cation, CH₃NH₃⁺) PSCs (33–36). Here we find that the interfacial Cl atoms on the TiO₂ NCs suppress deep trap states at the perovskite interface and thus considerably reduce interface recombination at TiO₂/perovskite contact. The interfacial Cl atoms also lead to strong electronic coupling and chemical binding at the TiO₂/perovskite planar junction, as projected in previous theoretical studies (37). As a result, we fabricated hysteresis-free planar PSCs with independently-certified PCEs of 20.1% for small-area devices (0.049 cm²) and 19.5% for large-area

devices (1.1 cm^2). The low-temperature planar PSCs with high initial PCE $>20\%$ exhibit excellent operational stability and retain 90% (97% after dark recovery) of their initial performance after 500 hours operating at their maximum power point under constant one-sun illumination.

We first examined defect passivation and interface binding by interfacial chlorine at the TiO_2 /perovskite interface using density functional theory (DFT) (Fig. 1, fig. S1, and table S1) (38). We found that Cl at the interface results in stronger binding at the TiO_2 /perovskite interface both for the cases of MAX- and PbX_2 -terminated ($X = \text{Cl}, \text{I}$) perovskite surfaces. Perovskite films with the PbX_2 -terminated interface are energetically favored to contact the TiO_2 . Previous studies (39–41) have shown that, in bulk perovskites, the most detrimental defects (deep level defects) are antisites, but that their formation energy is relatively high, explaining the low trap-state density in MAPbI_3 perovskite films and single crystals. Vacancies and interstitials, although much more abundant, are shallow defects. We thus explored the effect of Cl at the interface on both antisite and vacancy defects. Without Cl, a Pb-I antisite defect leads to localized states near the valence band edge (Fig. 1A). They can capture holes and become non-radiative recombination centers. In contrast, the formation energy of the Pb-Cl antisite at the PbCl_2 -terminated interface is higher (less favorable to form), indicating that antisite defects are suppressed in the presence of interfacial Cl atoms. The Pb-Cl antisite defect becomes much shallower and more delocalized (Fig. 1B) and has little effect on interface recombination. Overall, the incorporation of Cl atoms at the TiO_2 /perovskite interface resulted in a lower density of interfacial trap states (fig. S1, B and D) as well as stronger binding between TiO_2 and perovskite (table S1).

We devised a synthetic approach to obtain Cl-capped TiO_2 NCs as the electron-selective layer in solar cells. We first synthesized anatase TiO_2 NCs of size $\sim 5 \text{ nm}$ (fig. S2) (38) via a nonhydrolytic method through the reaction of TiCl_4 and benzyl alcohol at 85°C under ambient atmosphere (42, 43). This process results in Cl-capped TiO_2 NCs ($\text{TiO}_2\text{-Cl}$) with $12 \pm 2 \text{ at.}\%$ of Cl relative to Ti atoms as determined using x-ray photoelectron spectroscopy (XPS, Fig. 1C). A mixture of methanol and chloroform was used to disperse the NCs while preserving surface Cl-ligands. XPS confirmed that surface Cl-ligands were well-retained after we formed films from a methanol-chloroform cosolvent (Fig. 1C). In contrast, the surface Cl-ligands were detached from TiO_2 surfaces when the washed NCs were redispersed in ethanol with a stabilizer such as titanium diisopropoxide bis(acetylacetonate) (TiAcAc). Such TiO_2 NCs that lack Cl-ligands – the ESL materials used in previous reports (8, 9) – were taken as controls in the present study. Below, we denote the TiO_2 ESL with Cl-ligands as $\text{TiO}_2\text{-Cl}$; and the TiO_2

ESL lacking the Cl-ligands as TiO_2 . The Cl atoms were strongly bound to TiO_2 , and the Cl-ligands of TiO_2 thin film were retained on the surface after annealing up to 250°C (Fig. 1D).

We fabricated planar PSCs with TiO_2 as ESL with the device architecture of Fig. 2A. The $\text{TiO}_2\text{-Cl}$ film on ITO-coated glass obtained by spin-coating was smooth and pinhole-free (Fig. 2B and fig. S3A). The film also exhibited negligible parasitic absorption loss over the entire visible to near-infrared spectral range (fig. S3B). Post-annealing at moderate temperatures was applied to improve the quality of the spin-cast $\text{TiO}_2\text{-Cl}$ film. The best PV performance was achieved with a $\text{TiO}_2\text{-Cl}$ annealing temperature of 150°C (table S2 and fig. S4). The mixed cation/halide perovskite layer $\text{FA}_{0.85}\text{MA}_{0.15}\text{PbI}_{2.55}\text{Br}_{0.45}$, with a thickness of $\sim 600 \text{ nm}$, was deposited on the $\text{TiO}_2\text{-Cl}$ film using the anti-solvent method (38, 44, 45). The processing solvent for perovskite precursors (e.g., dimethylsulfoxide, DMSO) did not remove surface Cl-ligands from the $\text{TiO}_2\text{-Cl}$ film (fig. S5).

The bulk quality of perovskite films was similar on both $\text{TiO}_2\text{-Cl}$ and TiO_2 , a consequence of their identical processing. Smooth pinhole-free perovskite films with uniform and large grains were formed on both $\text{TiO}_2\text{-Cl}$ and TiO_2 (Fig. 2C and fig. S6). As expected from the stoichiometric ratio of the precursors, x-ray diffraction (XRD) spectra show no obvious PbI_2 nor other non-perovskite phases in films (Fig. 2D). The sharp absorption edge and narrow PL spectrum of the perovskite film confirm a homogenous and single-phase material (fig. S7). The perovskite films on both $\text{TiO}_2\text{-Cl}$ and TiO_2 exhibit a remarkably low trap state density of $\sim 3 \times 10^{15} \text{ cm}^{-3}$ as determined using the space-charge limit current (SCLC) method (fig. S8). The band alignment between $\text{TiO}_2\text{-Cl}$ (TiO_2) and perovskite was determined from ultraviolet photoelectron spectroscopy (UPS) and absorption measurements (fig. S9). The excellent match in conduction band minimum (CBM) between $\text{TiO}_2\text{-Cl}$ and perovskite allowed efficient electron transfer into $\text{TiO}_2\text{-Cl}$, while the high offset in valence band maximum (VBM) provided efficient hole blocking.

We studied the charge transfer kinetics between perovskite and ESL using steady-state and time-resolved photoluminescence (TR-PL) spectroscopy. When perovskite films were formed on TiO_2 and $\text{TiO}_2\text{-Cl}$, the steady-state PL was quenched because of fast electron transfer to ESLs (Fig. 2E). Figure 2F shows the PL decays of the perovskite films on bare glass and on the TiO_2 and $\text{TiO}_2\text{-Cl}$ coated ITO glass substrates. Table S3 summarizes the decays fit for biexponential components, a fast decay lifetime τ_1 , and a slow decay lifetime τ_2 . The perovskite film on bare glass showed a long lifetime (τ_2) of 470 ns. The PL lifetimes of perovskite films on ESLs were shortened to a similar degree for both TiO_2 and $\text{TiO}_2\text{-Cl}$. This result indicates that both ESLs had

sufficient electron extraction in solar cells, consistent with the good band alignments between the ESLs and perovskite.

To explore the effect of interfacial Cl atoms on the PV performance of planar PSCs, we made devices on the TiO₂-Cl and control TiO₂ ESLs. Figure S10 presents the statistical performance of 40 devices fabricated with otherwise-identical device processing on each type of ESL. Solar cells fabricated on TiO₂-Cl exhibit considerably better performance than those on TiO₂ for all PV metrics: the average V_{oc} increased from 1.06 V to 1.14 V with the incorporation of Cl; and the average FF increased from 69% to 77%. Correspondingly, TiO₂-Cl resulted in a higher average PCE (19.8%) than the Cl-free TiO₂ (15.8%).

Device performance measured after optimization is shown in Fig. 3A and table S4. These results confirm that the interfacial Cl-atoms, not the bulk properties of TiO₂ ESLs, dominate the performance of these perovskite solar cells. Figure 3B shows a histogram of PCE values over 200 planar PSCs fabricated on TiO₂-Cl within a period of 3 months. Excellent reproducibility is indicated by the narrow distribution of PCE values. The best-performing devices with TiO₂-Cl reached a PCE of 20.9%. The PCE from J - V sweeps is consistent with the stabilized maximum power output (fig. S11). The EQE spectrum (fig. S12) exhibited a broad plateau above 80% over the spectral range from 400 to 760 nm because of strong light harvesting within the thick perovskite film. Integration of the EQE curve with the AM1.5G solar spectrum yielded a photocurrent density of 22.6 mA cm⁻², in good agreement with the J_{sc} value from J - V characterization. We also examined the hysteresis of solar cells made on TiO₂-Cl and TiO₂ (Fig. 3A and table S4). Devices on TiO₂-Cl showed negligible hysteresis, while devices made on TiO₂ exhibit strong hysteresis, similar to previous reports using low-temperature TiO₂ as ETL (8, 9). The PV parameters of the Cl-free devices varied substantially with respect to scan direction.

To gain further insight into the performance enhancement resulting from the use of TiO₂-Cl, we characterized perovskite film properties, charge transfer kinetics, and charge recombination in solar cells with TiO₂ and TiO₂-Cl. The bulk quality of perovskite films and charge transfer were similar on both ESLs. Transient photocurrent decay under short-circuit conditions was obtained to study the influence of the ESL on charge transfer in solar cells (Fig. 3C). Cells with the two ESLs had comparable charge transport lifetime ($\tau_t \sim 3.4 \mu\text{s}$), indicating similar interfacial charge transfer. This similarity indicates that either bulk quality or interface charge transfer is not the main reason for the solar cell performance enhancement by TiO₂-Cl.

We characterized solar cells using transient photovoltage decay under the open-circuit condition and found that the charge recombination lifetime (τ_r) of the device on TiO₂-Cl

was substantially longer than that of the device on TiO₂ (145 μs versus 64 μs ; Fig. 3D), consistent with slowed charge recombination at the TiO₂-Cl/perovskite interface. The reduced ideality factor of solar cells with TiO₂-Cl ($n = 1.25$) compared to TiO₂ ($n = 1.73$) is consistent with suppressed interfacial recombination (fig. S13). As seen in the DFT studies, interfacial Cl atoms suppress the formation of deep trap states on the surface of perovskite films, leading to improved surface passivation and reduced interfacial recombination.

To examine the applicability of TiO₂-Cl to other high-efficiency PSCs, we fabricated devices using cesium-containing perovskite Cs_{0.05}FA_{0.81}MA_{0.14}PbI_{2.55}Br_{0.45} (denoted as CsMAFA), which had been shown to improve performance and photostability compared to FA_{0.85}MA_{0.15}PbI_{2.55}Br_{0.45} (denoted as MAFA) (22, 46, 47). The best-performing small-area CsMAFA solar cell (0.049 cm²) exhibited a high laboratory PCE of 21.4% ($V_{oc} = 1.189$ V, $J_{sc} = 22.3$ mA/cm², FF = 0.806) without hysteresis in J - V sweeps (Fig. 3E). We also fabricated large-area (1.1 cm²) CsMAFA solar cells on TiO₂-Cl, showing a PCE value >20% with negligible hysteresis (Fig. 3F). A small-area and a large-area device were sent, without encapsulation, to an accredited independent PV test laboratory (Newport Corporation PV Lab, MT, USA) for certification. They gave certified PCEs of 20.1% and 19.5%, respectively (figs. S14 to S16). The large-area device exhibited ~3% performance loss relative to the small-area device. The certified PCE of 19.5% for large-area, low-temperature planar PSC exceeds that of other reported low-temperature or planar PSCs (24, 25), and it approaches the certified PCE of large-area cells that relied on high-temperature-sintered mesoporous TiO₂ (table S5) (23, 38, 48).

We examined the long-term stability of low-temperature planar PSCs made on TiO₂-Cl and TiO₂ under dark storage as well as under operating conditions. The long-term stability of PSCs is closely related to the front ESL/perovskite interface binding strength and interfacial charge accumulation during operation (49, 50). The devices made on TiO₂-Cl showed substantially enhanced stability relative to TiO₂ under dark storage (Fig. 4A). MAFA based devices on TiO₂-Cl maintained 95% of their initial PCE after storage in the dark over 60 days, while those on TiO₂ only retained 38% of their initial efficiency (Fig. 4A). The high-efficiency CsMAFA devices on TiO₂-Cl (initial PCE>21%) exhibited promising shelf stability, retaining 96% of their initial performance after 90 days (over 2,000 hours).

Solar cells must operate stably under maximum power point (MPP) conditions. The MAFA solar cells based on TiO₂-Cl showed improved stability under continuous operation at MPP compared to devices based on TiO₂ (fig. S17). Impressively, the CsMAFA solar cell on TiO₂-Cl (with 420-

nm cutoff UV filter) retained 90% of their initial performance after continuous operation for 500 hours under one-sun illumination, as directly determined from the MPP tracking (Fig. 4B). The PCE increased slightly in the first tens of hours of MPP operation, which may be caused by light-induced defect healing in the perovskite active layer (19, 51). No perovskite decomposition was observed after MPP operation as seen from XRD (fig. S18), indicating that the performance drop during MPP operation may be caused by defect generation in the perovskite layer (52, 53) and changes to the perovskite/Spiro-OMeTAD interface (the latter has previously been shown to be vulnerable) (54–56). The device self-recovered to an efficiency of 19.8% (97% of initial PCE) following dark storage (Fig. 4C), consistent with previous reports (18, 19, 52).

Overall, the stronger binding at the TiO₂-Cl/perovskite interface and the suppressed interfacial recombination account for superior stability in planar PSCs based on TiO₂-Cl. The new approach to fabricate efficient and stable perovskite solar cells is simple and scalable, compatible with future industrialization of perovskite-based PV technology. It offers a promising path to flexible devices and to combining with low-band-gap semiconductor materials to form tandem devices.

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SUPPLEMENTARY MATERIALS

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Materials and Methods

Figs. S1 to S18

Tables S1 to S5

References (57–59)

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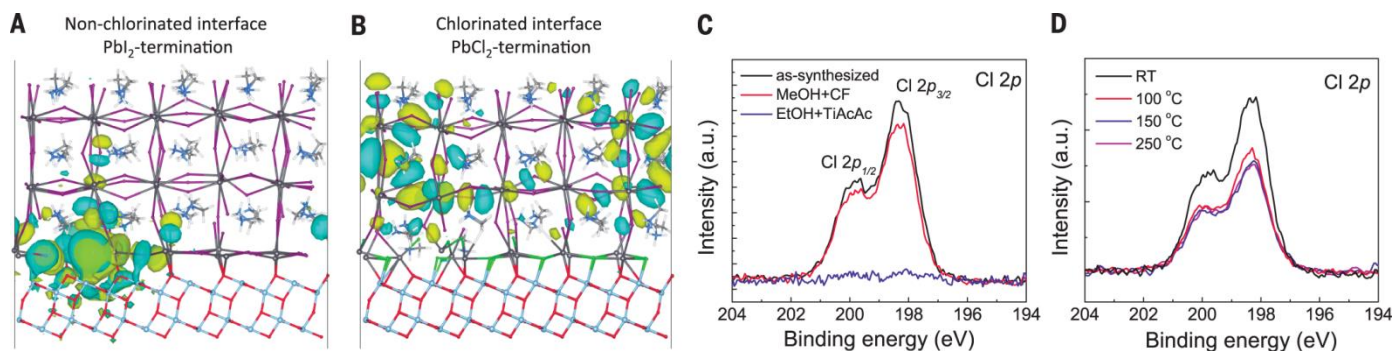


Fig. 1. The effect of Cl on interface quality between perovskite and TiO₂, and stabilization of Cl-capped TiO₂ (TiO₂-Cl) colloidal nanocrystals. (A) Trap-like localized antisite defects form near the valence band edge for the PbI₂-terminated TiO₂/perovskite interface. (B) Shallow and delocalized Pb-Cl antisite defects are seen for the PbCl₂-terminated interface. (C and D) XPS spectra of Cl 2p peak of (C) TiO₂ NC films: as-synthesized, redispersed in the cosolvent of methanol and chloroform (MeOH + CF), redispersed in ethanol with titanium diisopropoxide bis(acetylacetonate) as stabilizer (EtOH + TiAcAc) and (D) TiO₂-Cl NC films with various post-annealing temperatures: room temperature (RT), 100 °C, 150 °C, and 250 °C.

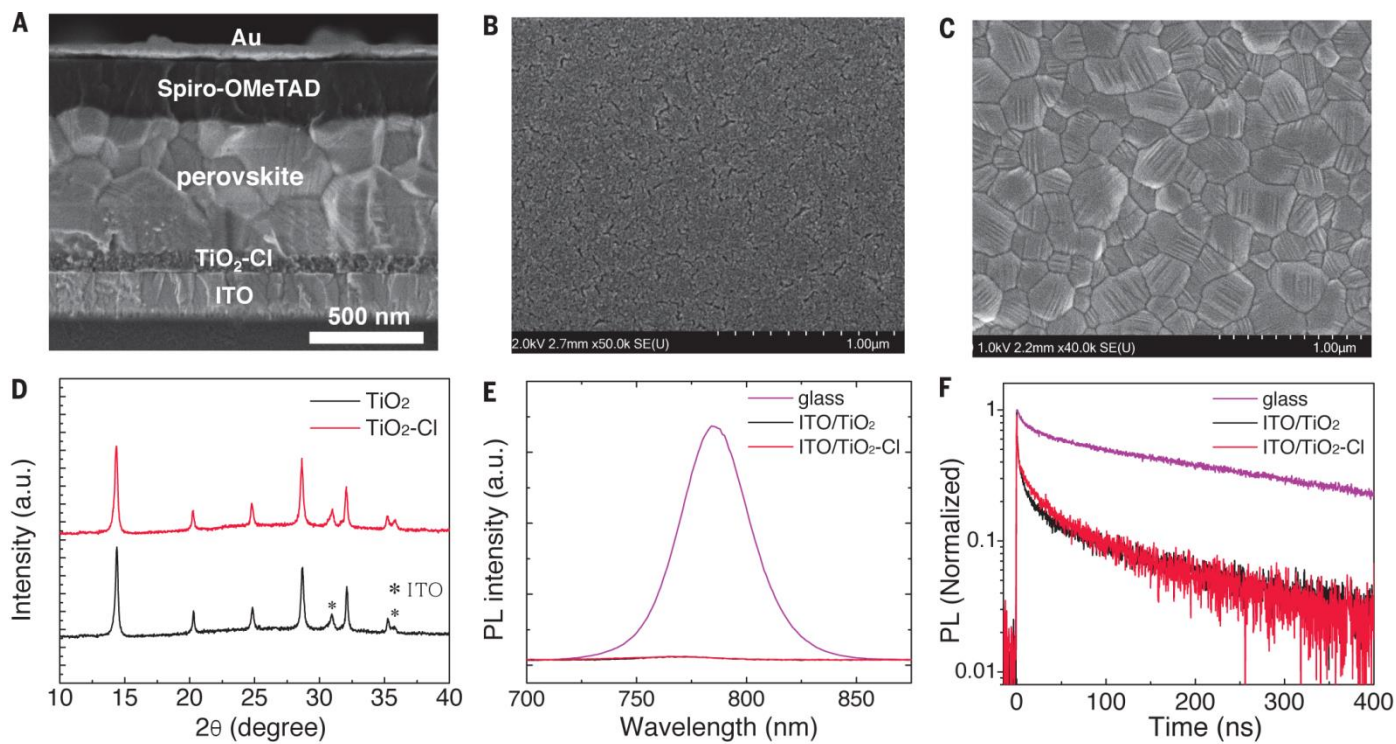


Fig. 2. Device structure and characterization of perovskite films on $\text{TiO}_2\text{-Cl}$. (A) Device structure and cross-sectional scanning electron microscopy (SEM) image of planar PSC. (B and C) Top-view SEM images of the $\text{TiO}_2\text{-Cl}$ film on ITO substrate (B) and the perovskite film on $\text{TiO}_2\text{-Cl}$ (C). (D) XRD patterns of perovskite films on TiO_2 and $\text{TiO}_2\text{-Cl}$. (E) Steady-state PL spectra and (F) time-resolved PL decays of perovskite films on bare glass, and on TiO_2 and $\text{TiO}_2\text{-Cl}$ coated ITO substrates. The PL signals of perovskite films on TiO_2 and $\text{TiO}_2\text{-Cl}$ were effectively quenched by the fast charge extraction by TiO_2 and $\text{TiO}_2\text{-Cl}$.

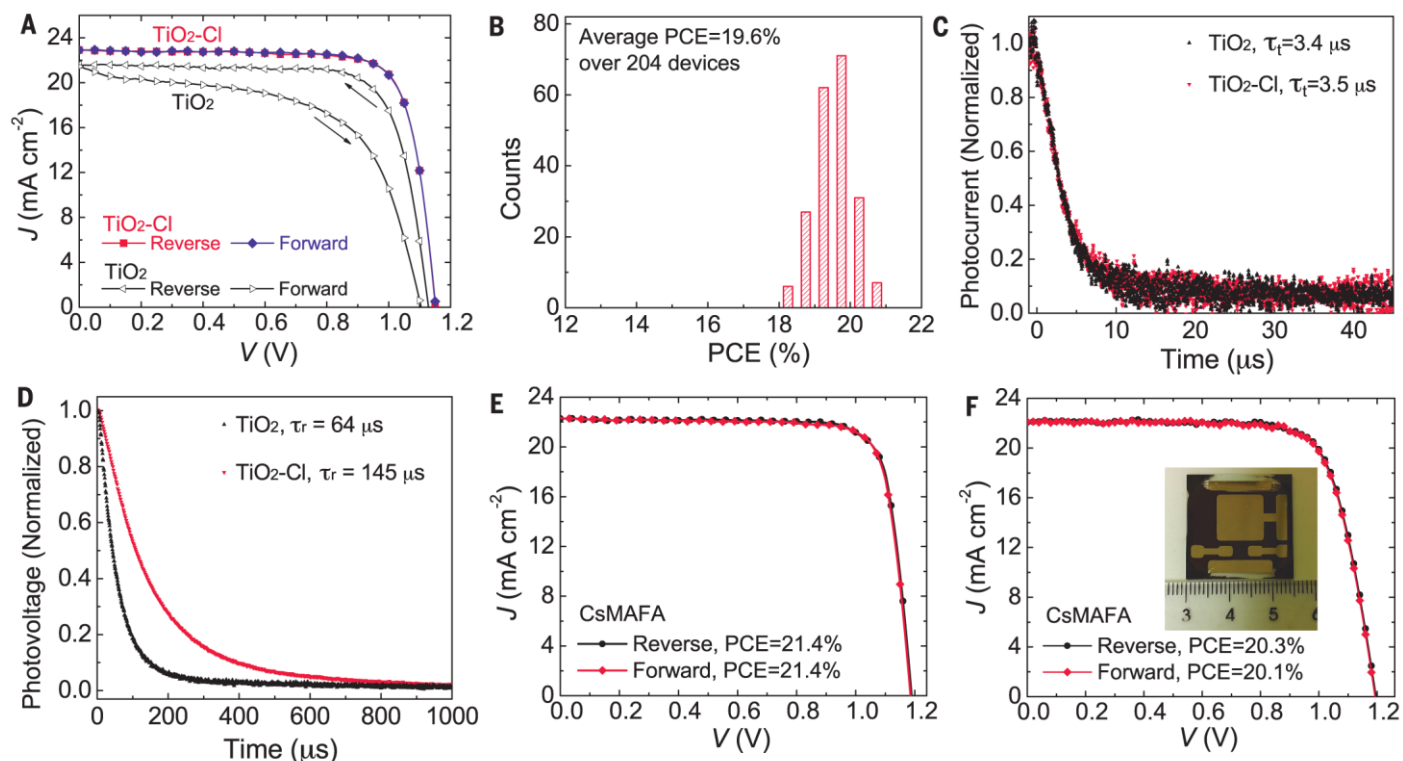


Fig. 3. Enhanced photovoltaic performance of perovskite solar cells with $\text{TiO}_2\text{-Cl}$. (A) J - V curves of PSCs with TiO_2 and $\text{TiO}_2\text{-Cl}$ as ESLs measured at reverse and forward scans. (B) Histogram of the PCE values among 204 devices on $\text{TiO}_2\text{-Cl}$. (C) Normalized transient photocurrent decay and (D) normalized transient photovoltage decay of solar cells with TiO_2 and $\text{TiO}_2\text{-Cl}$ as ESLs. Devices shown in A-D have perovskite composition of MAFA. (E) J - V curves of best-performing small-area (0.049 cm^2) CsMAFA PSC measured at reverse and forward scans. (F) J - V curves of best-performing large-area (1.1 cm^2) CsMAFA PSC showing a PCE of 20.3% ($V_{oc} = 1.196 \text{ V}$, $J_{sc} = 22.2 \text{ mA cm}^{-2}$, $\text{FF} = 76.4\%$) at reverse scan. The inset shows the photo of the large-area device. MAFA and CsMAFA denote the perovskite compositions of $\text{FA}_{0.85}\text{MA}_{0.15}\text{PbI}_{2.55}\text{Br}_{0.45}$ and $\text{Cs}_{0.05}\text{FA}_{0.81}\text{MA}_{0.14}\text{PbI}_{2.55}\text{Br}_{0.45}$, respectively.

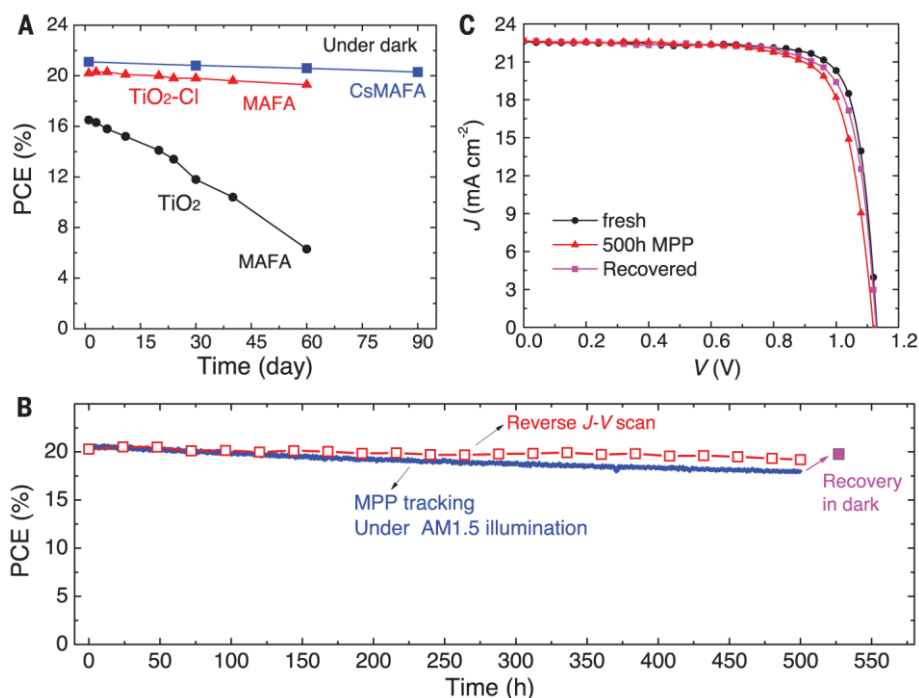


Fig. 4. Long-term device stability of perovskite solar cells with $\text{TiO}_2\text{-Cl}$ and TiO_2 . (A) Dark storage stability of non-encapsulated PSCs using TiO_2 and $\text{TiO}_2\text{-Cl}$. The unsealed cells were kept in a dry cabinet (<30% relative humidity) in the dark and measured regularly in nitrogen. PCE values were obtained from the reverse scans. MAFA and CsMAFA represent the perovskite compositions of $\text{FA}_{0.85}\text{MA}_{0.15}\text{PbI}_{2.55}\text{Br}_{0.45}$ and $\text{Cs}_{0.05}\text{FA}_{0.81}\text{MA}_{0.14}\text{PbI}_{2.55}\text{Br}_{0.45}$, respectively. (B) Continuous maximum power point (MPP) tracking for 500 hours of a high-performance unsealed CsMAFA cell with $\text{TiO}_2\text{-Cl}$ in nitrogen atmosphere under constant simulated solar illumination (100 mW cm^{-2}) with a 420 nm cutoff UV filter. PCE values taken from reverse J - V scans (square symbols) are shown as well; the device retains 95% of initial performance as determined from reverse J - V scans. (C) J - V curves of PSC (CsMAFA) shown in (B) at various stages: fresh, right after 500 hours of MPP operation, and after recovery overnight in the dark. The J - V curves were measured without UV-filter



Efficient and stable solution-processed planar perovskite solar cells via contact passivation

Hairen Tan, Ankit Jain, Oleksandr Voznyy, Xinzheng Lan, F. Pelayo García de Arquer, James Z. Fan, Rafael Quintero-Bermudez, Mingjian Yuan, Bo Zhang, Yicheng Zhao, Fengjia Fan, Peicheng Li, Li Na Quan, Yongbiao Zhao, Zheng-Hong Lu, Zhenyu Yang, Sjoerd Hoogland and Edward H. Sargent (February 2, 2017)
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Editor's Summary

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